

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

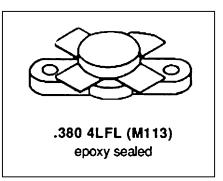
PHONE: (215) 631-9840 FAX: (215) 631-9855

SD1224-02

# RF AND MICROWAVE TRANSISTORS VHF FM APPLICATIONS

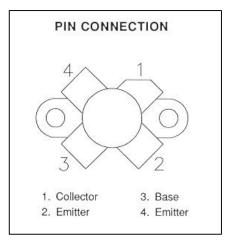
### **Features**

- 175 MHz
- 28 VOLTS
- CLASS C
- **COMMON EMITTER**
- EFFICIENCY 60% MIN.
- P<sub>OUT</sub> = 40 W MIN.
- G<sub>P</sub> = 7.6 dB GAIN



#### **DESCRIPTION:**

The SD1224-02 is an epitaxial silicon NPN planar transistor designed primarily for 28 V FM Class C RF amplifiers utilized in ground station transmitters. This device utilizes ballasted emitter resistors and improved metallization systems to achieve optimum load mismatch capability.



### ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	65	V
V <sub>CEO</sub>	Collector-Emitter Voltage	35	V
V <sub>CES</sub>	Collector-Emitter Voltage	65	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ic	Device Current	5.0	Α
P <sub>DISS</sub>	Power Dissipation	60	W
TJ	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

### Thermal Data

_							
	$R_{TH(j-c)}$	Junction-Case Thermal Resistance	2.9	°C/W			





# ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

## **STATIC**

Symbol	Test Conditions		Value			
		Min.	Тур.	Max.	Units	
BV <sub>CBO</sub>	I <sub>C</sub> = 200 mA	$I_B = 0 \text{ mA}$	65			٧
BV <sub>CES</sub>	I <sub>C</sub> = 200 mA	$V_{BE} = 0 V$	65			٧
BV <sub>CEO</sub>	I <sub>C</sub> = 200 mA	I <sub>B</sub> = 0 mA	35			٧
BV <sub>EBO</sub>	I <sub>E</sub> = 10 mA	I <sub>C</sub> = 0 mA	4.0			٧
$\mathbf{I}_{CBO}$	V <sub>CB</sub> = 30 V	I <sub>E</sub> = 0 mA			1	mA
h <sub>FE</sub>	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 500 mA	5			

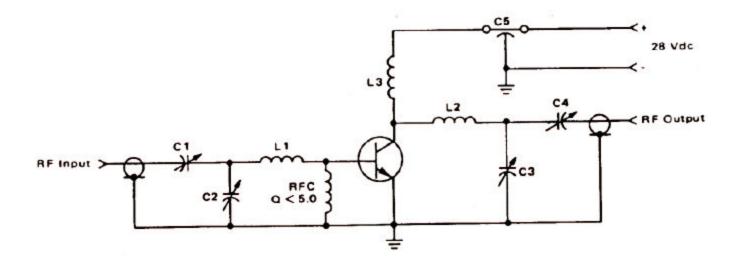
### **DYNAMIC**

Comb al	Symbol Test Conditions			Value			
Symbol			Min.	Тур.	Max.	Units	
P <sub>out</sub>	f = 175 MHz	P <sub>IN</sub> = 7.0 W	V <sub>CE</sub> = 28 V	40			W
ης	f = 175 MHz	$P_{IN} = 7.0 W$	V <sub>CE</sub> = 28 V	60			%
G₽	f = 175 MHz	P <sub>IN</sub> = 7.0 W	V <sub>CE</sub> = 28 V	7.6			dB
Сов	f = 1 MHz	V <sub>CB</sub> = 30 V				65	pF





### **TEST CIRCUIT**



C1,C2, C3,C4: ARCO 464, 25-280pF

C5 : 0.1µF

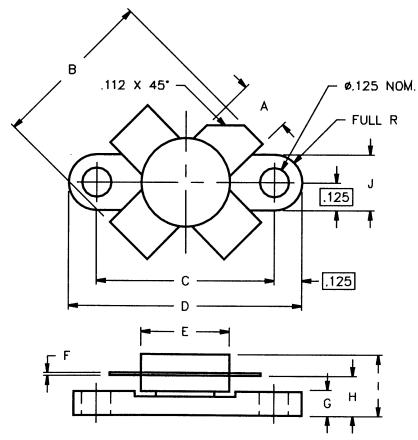
L1 : 1" Straight #16 AWG L2 : 1 Turn, #16 AWG, 1/4" I.D.

L3 : 0.22µH





## PACKAGE MECHANICAL DATA



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
Α	.220/5,59	.230/5,84	T		.260/7,11
В	.785/19,94		J	.240/6,10	.255/6,48
С	.720/18,29	.730/18,54			
D	.970/24,64	.980/24,89			
Ε		.385/9,78			
F	.004/0,10	.006/0,15			
G	.085/2,16	.105/2,67			
Н	.160/4,06	.180/4,57			